Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
0.357 inches	
Terminal Length:	
1.000 inches	
Overall Diameter:	
0.235 inches	
Function For Which	Designed:
Bidirectional and trans	sient suppressor
Joint Electronic Dev	ice Engineering Council/jedec/case Outline Designation:
Do-13	
Electrode Internally-	electrically Connected To Case:
Cathode	
Mounting Method:	
Terminal	
Semiconductor Mate	erial:
Silicon	
Voltage Rating In Vo	Its Per Characteristic:
15.2 breakdown volta	ige, dc and 16.8 breakdown voltage, dc
Current Rating Per 0	Characteristic:
5.00 microamperes fc	rward current, average peak
Power Rating Per Cl	naracteristic:
1.0 watts small-signal	input power, common-collector major
Maximum Operating	Tempurature Per Measurement Point:
175.0 degrees celsius	ambient air
Test Data Document	:
81349-mil-s-19500 sp	ecification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificatio
format; excludes com	mercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and pe	rformance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And	Quantity:
2 uninsulated wire lea	d
Specification Data:	
81349-mil-s-19500/50	7 government specification
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
No	
Fiig:	
A110a0	